

The ITZ15F12 is a very robust non punch through n-channel, enhancement mode insulated gate bipolar transistor (IGBT) designed for low power dissipation in a wide range of high voltage applications such as power supplies and motor drives. The high impedance gate simplifies gate drive considerations, allowing operation directly from low power control circuitry.

The device is optimised for high frequency operation with fast rise and fall times. The product is suitable for modern systems employing switching frequencies up to and beyond the audible spectrum.

Low saturation voltages minimise power dissipation, thereby reducing the cost of the overall system in which they are used.

The ITZ is fully short circuit rated making it especially suited for motor control and other applications requiring short circuit withstand capability. Each device in the Powerline range is available with or without an integral anti-parallel ultrafast soft recovery diode, see separate datasheet for co-pack device.

Typical applications include high frequency inverters for motor control, pwm, welding and heating apparatus. The Powerline range of IGBTs is also applicable to switched mode (SMPS) and uninterruptible power supplies (UPS).

FEATURES

- Enhancement Mode n-Channel Device
- Non Punch Through Structure
- High Switching Speed
- Low On-state Saturation Voltage
- High Input Impedance Simplifies Gate Drive
- Fully Short Circuit Rated To 10µs
- Square RBSOA

APPLICATIONS

- High Frequency Inverters
- Motor Control
- Switched Mode Power Supplies
- High Frequency Welding
- UPS Systems
- PWM Drives

KEY PARAMETERS

| | | |
|---------------|-------|-------|
| V_{CES} | (max) | 1200V |
| $V_{CE(sat)}$ | (typ) | 2.8V |
| I_{C25} | (max) | 28A |
| I_{C85} | (max) | 15A |
| I_{CM} | (max) | 45A |
| t_{sc} | (max) | 10µs |

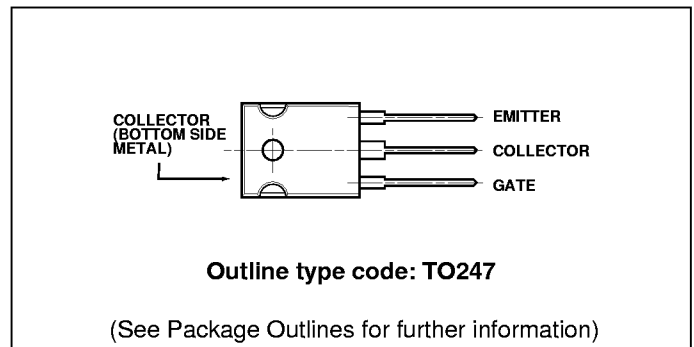


Fig.1 Pin connections - top view (not to scale)

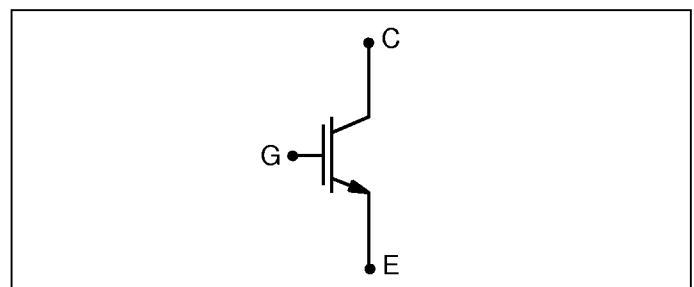


Fig.2 ITZ15F12 circuit

ORDERING INFORMATION

ITZ15F12P TO247

Note: When ordering, use the complete part number.

ITZ15F12

ABSOLUTE MAXIMUM RATINGS

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device.

T_{case} = 25°C unless stated otherwise.

| Symbol | Parameter | Test Conditions | Max. | Units |
|------------------|------------------------------|-------------------------------|------|-------|
| V _{CES} | Collector-emitter voltage | V _{GE} = 0V | 1200 | V |
| V _{GES} | Gate-emitter voltage | - | ±20 | V |
| I _{C25} | Continuous collector current | T _{case} = 25°C | 28 | A |
| I _{C85} | Continuous collector current | T _{case} = 85°C | 15 | A |
| I _{CM} | Pulsed collector current | 1ms, T _{case} = 85°C | 45 | A |
| P _{tot} | Power dissipation | T _{case} = 85°C | 80 | W |

THERMAL AND MECHANICAL RATINGS

| Symbol | Parameter | Conditions | Min. | Max. | Units |
|----------------------|--------------------------------------|---------------------|------|------|-------|
| R _{th(j-c)} | Thermal resistance | DC junction to case | - | 0.8 | °C/W |
| T _{OP} | Operating junction temperature range | - | −40 | 150 | °C |
| T _{slg} | Storage temperature range | - | −40 | 150 | °C |
| - | Mounting torque | M3 screw | - | 1.1 | Nm |

DC ELECTRICAL CHARACTERISTICS

T_{case} = 25°C unless stated otherwise.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|----------------------|--------------------------------------|---|------|------|------|-------|
| I _{CES} | Collector cut-off current | V _{GE} = 0V, V _{CE} = 1200V | - | - | 1 | mA |
| I _{GES} | Gate leakage current | V _{GE} = 20V, V _{CE} = 0V | - | - | ±500 | nA |
| V _{GE(TH)} | Gate threshold voltage | I _C = 1mA, V _{CE} = V _{GE} | 4.5 | 6 | 7.5 | V |
| V _{CE(SAT)} | Collector-emitter saturation voltage | V _{GE} = 15V, I _C = 15A | - | 2.8 | 3.3 | V |
| | | V _{GE} = 15V, I _C = 15A, T _j = 125°C | - | 3.6 | - | V |

AC ELECTRICAL CHARACTERISTICS

$T_{\text{case}} = 25^{\circ}\text{C}$ unless stated otherwise.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|------------------|------------------------------|---|------|------|------|-------|
| C_{ies} | Input capacitance | $V_{\text{CE}} = 25\text{V}, V_{\text{GE}} = 15\text{V}, f = 1\text{MHz}$ | - | 2160 | - | pF |
| C_{oes} | Output capacitance | $V_{\text{CE}} = 25\text{V}, V_{\text{GE}} = 15\text{V}, f = 1\text{MHz}$ | - | 215 | - | pF |
| C_{res} | Reverse transfer capacitance | $V_{\text{CE}} = 25\text{V}, V_{\text{GE}} = 15\text{V}, f = 1\text{MHz}$ | - | 10 | - | pF |

INDUCTIVE SWITCHING CHARACTERISTICS - see figures 3 to 5

$T_{\text{case}} = 25^{\circ}\text{C}$ unless stated otherwise.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|---------------------|----------------------------------|--|------|------|------|---------------|
| $t_{\text{d(ON)}}$ | Turn-on delay time | $I_{\text{C}} = 15\text{A},$ $V_{\text{GE}} = \pm 15\text{V},$ $V_{\text{CE}} = 50\% V_{\text{ces}}$ $R_{\text{G(ON)}} = R_{\text{G(OFF)}} = 5\Omega$ | - | 30 | - | ns |
| t_{r} | Rise time | | - | 15 | - | ns |
| E_{ON} | Turn-on energy loss - per cycle | | - | 750 | - | μJ |
| $t_{\text{d(OFF)}}$ | Turn-off delay time | | - | 110 | - | ns |
| t_{f} | Fall time | | - | 50 | - | ns |
| E_{OFF} | Turn-off energy loss - per cycle | | - | 1500 | - | μJ |

$T_{\text{case}} = 125^{\circ}\text{C}$ unless stated otherwise.

| | | | | | | |
|---------------------|----------------------------------|--|---|------|---|---------------|
| $t_{\text{d(ON)}}$ | Turn-on delay time | $I_{\text{C}} = 15\text{A},$ $V_{\text{GE}} = \pm 15\text{V},$ $V_{\text{CE}} = 50\% V_{\text{ces}}$ $R_{\text{G(ON)}} = R_{\text{G(OFF)}} = 5\Omega$ | - | 30 | - | ns |
| t_{r} | Rise time | | - | 15 | - | ns |
| E_{ON} | Turn-on energy loss - per cycle | | - | 1400 | - | μJ |
| $t_{\text{d(OFF)}}$ | Turn-off delay time | | - | 160 | - | ns |
| t_{f} | Fall time | | - | 60 | - | ns |
| E_{OFF} | Turn-off energy loss - per cycle | | - | 1900 | - | μJ |

For additional switching information please refer to figures 8 to 13.

SHORT CIRCUIT RATING

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|-----------------|------------------------------|---|------|------|------|---------------|
| t_{sc} | Short circuit withstand time | $T_{\text{c}} = 125^{\circ}\text{C}, V_{\text{GE}} = 15\text{V}, V_{\text{CE}} = 80\% V_{\text{CES}}$ | - | - | 10 | μs |

Caution: These devices are sensitive to electrostatic discharge. Users should observe proper ESD handling precautions.

BASIC TEST CIRCUIT AND SWITCHING DEFINITIONS

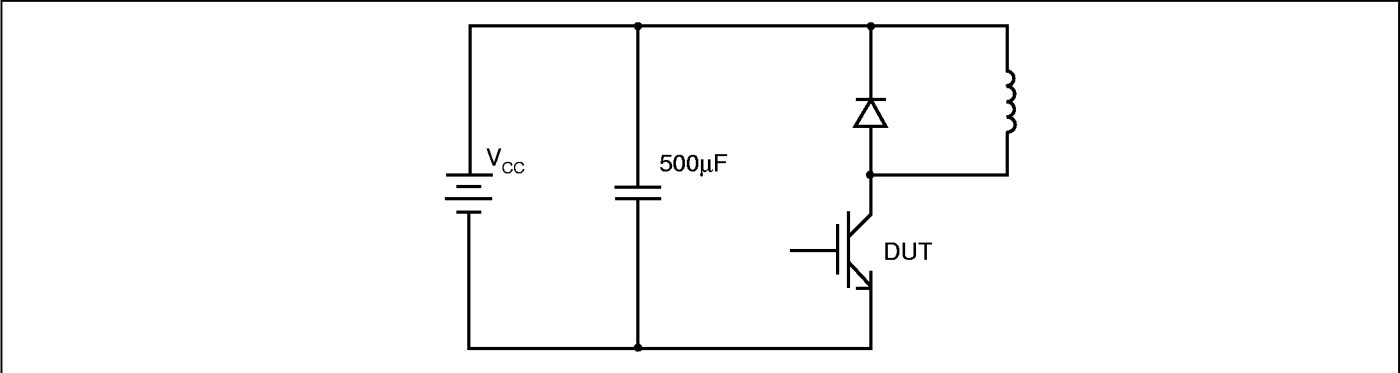


Fig.3 Basic d.c. chopper circuit

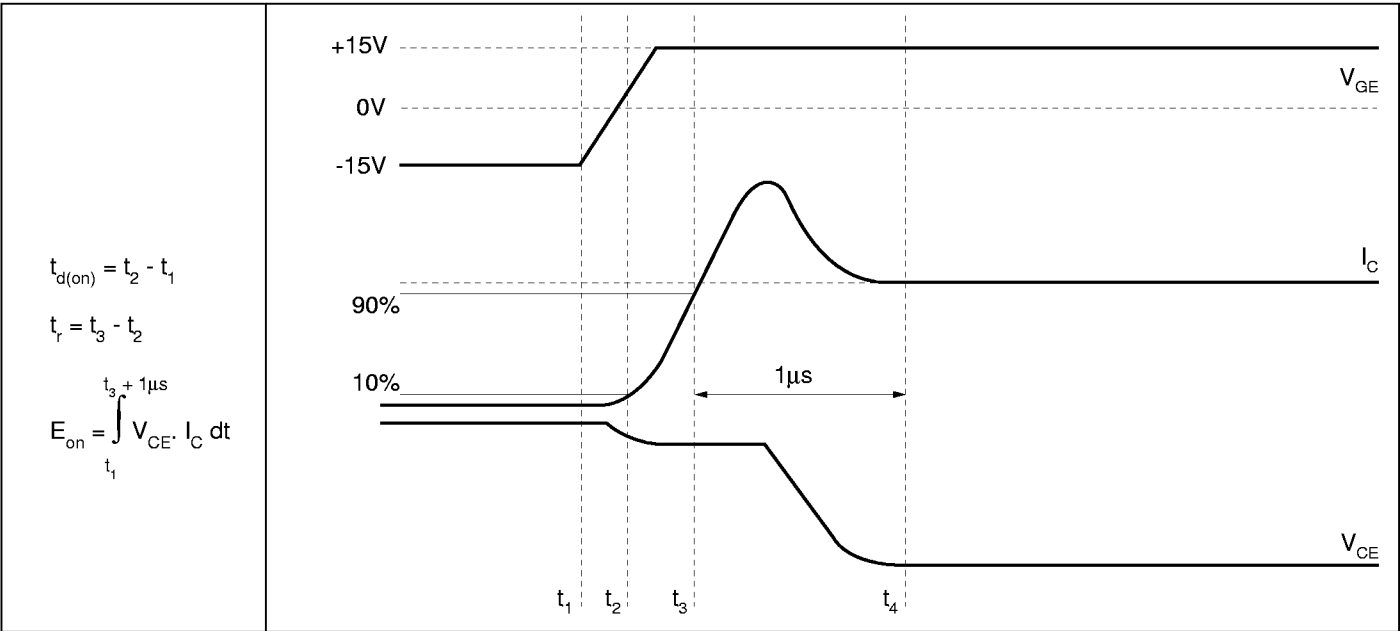


Fig.4 Turn-on characteristics

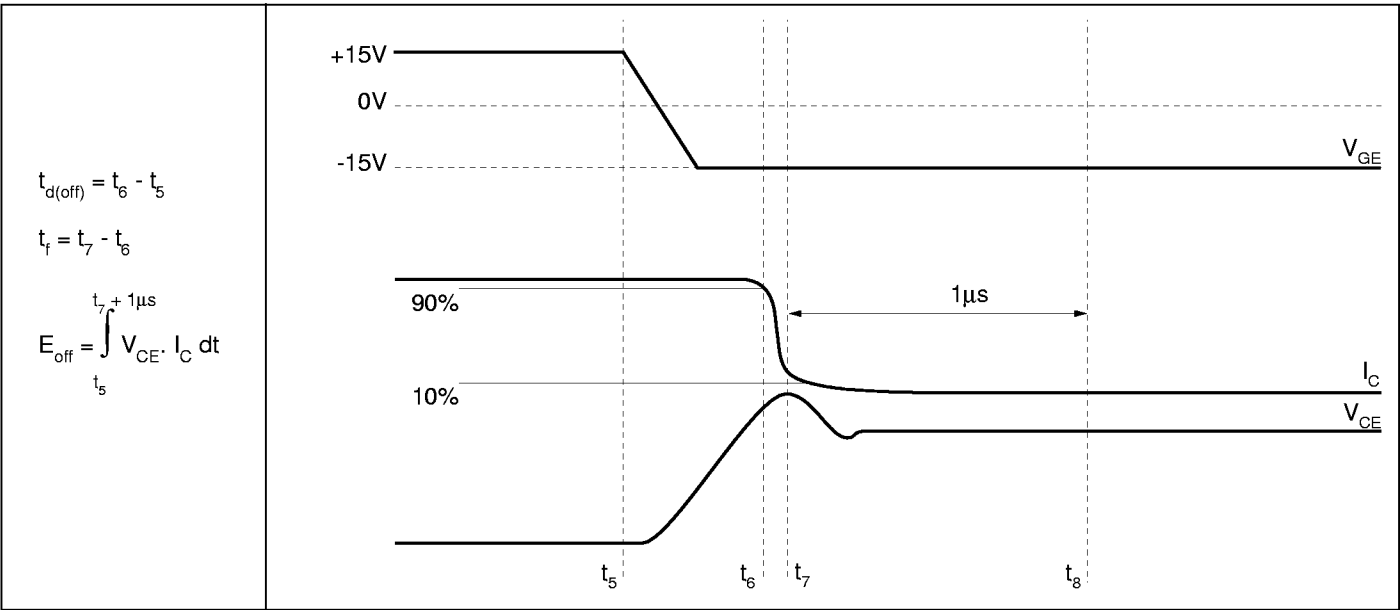


Fig.5 Turn-off characteristics

CURVES

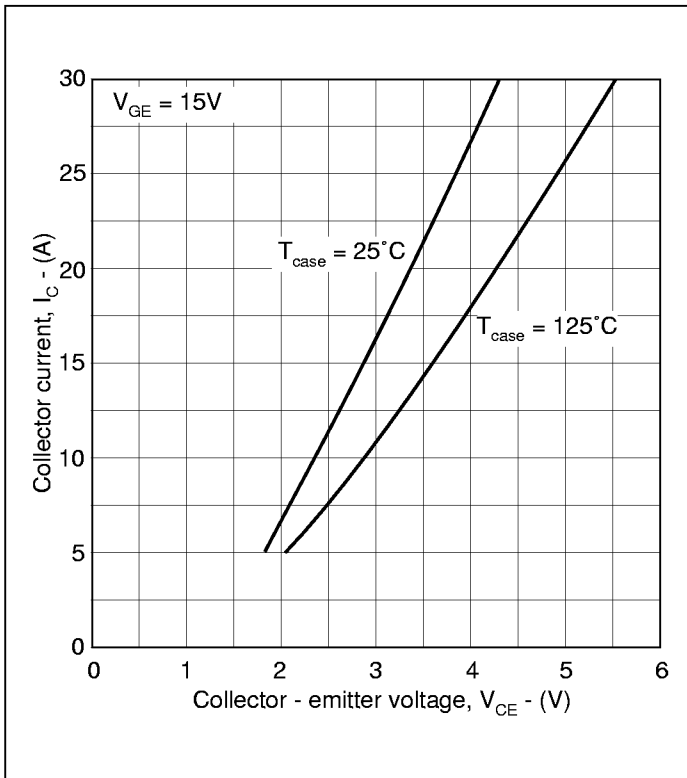


Fig.6 Typical output characteristics

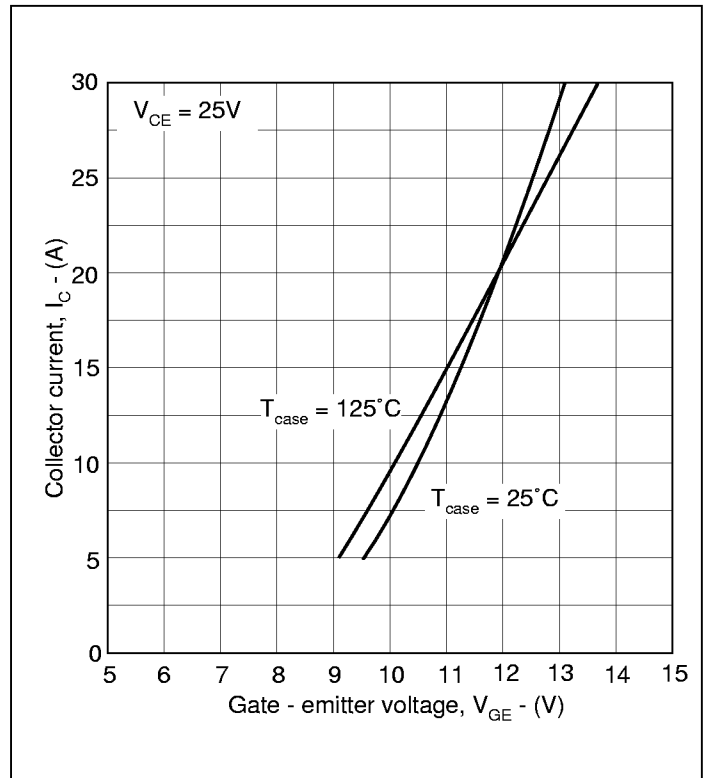


Fig.7 Typical transfer characteristics

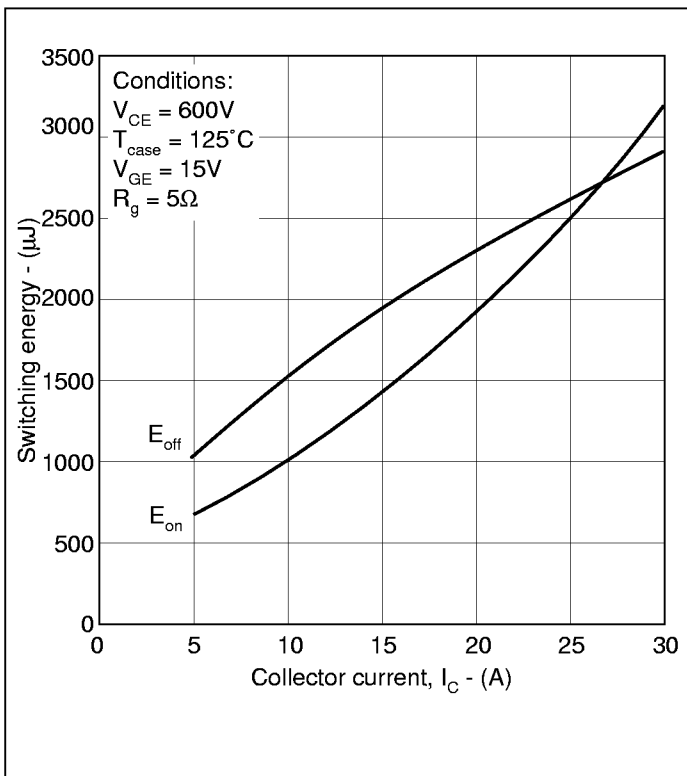


Fig.8 Typical switching losses vs collector current

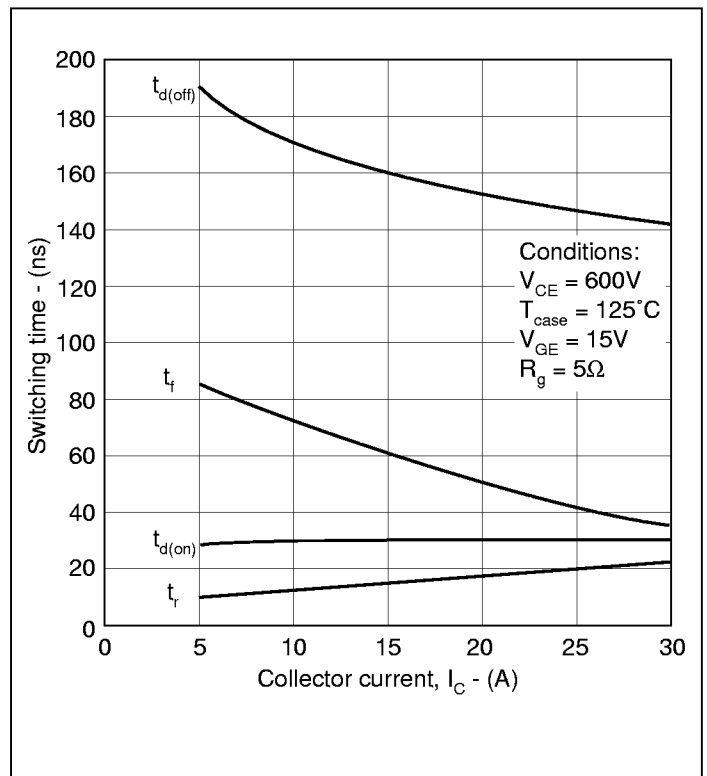


Fig.9 Typical switching times vs collector current

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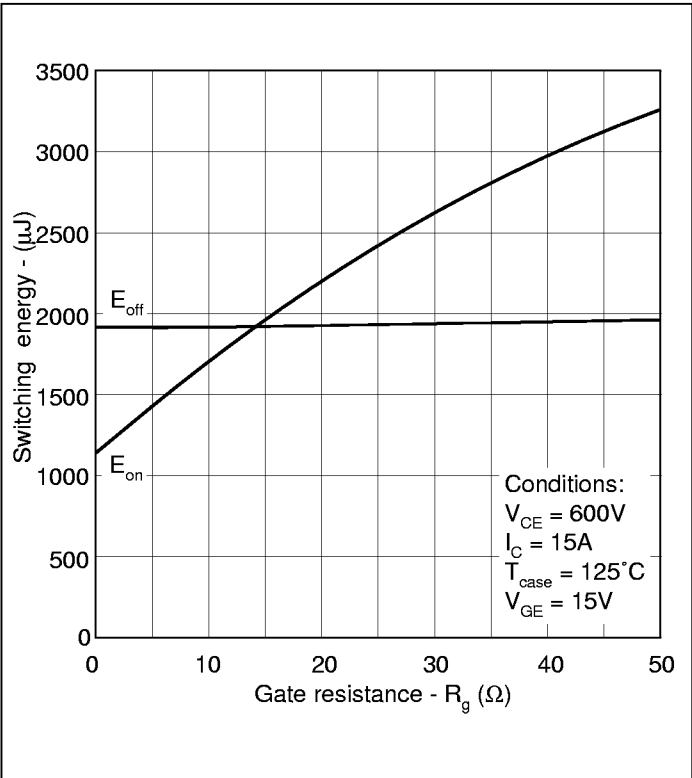


Fig.10 Typical switching losses vs gate resistance

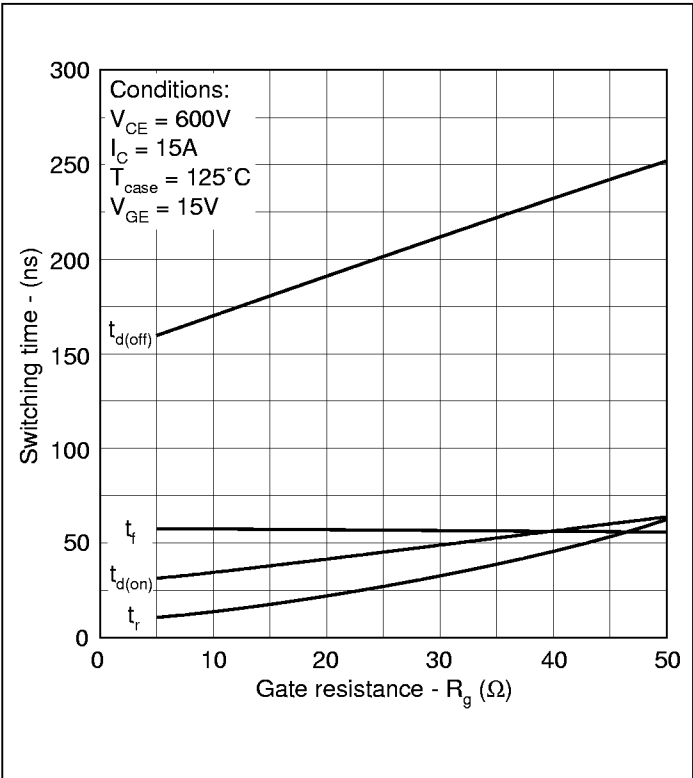


Fig.11 Typical switching times vs gate resistance

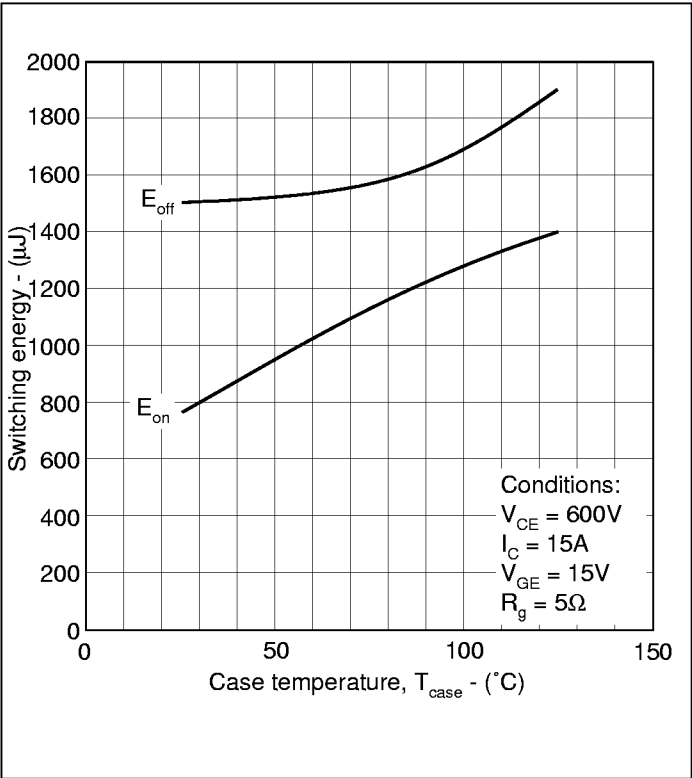


Fig.12 Typical switching losses vs case temperature

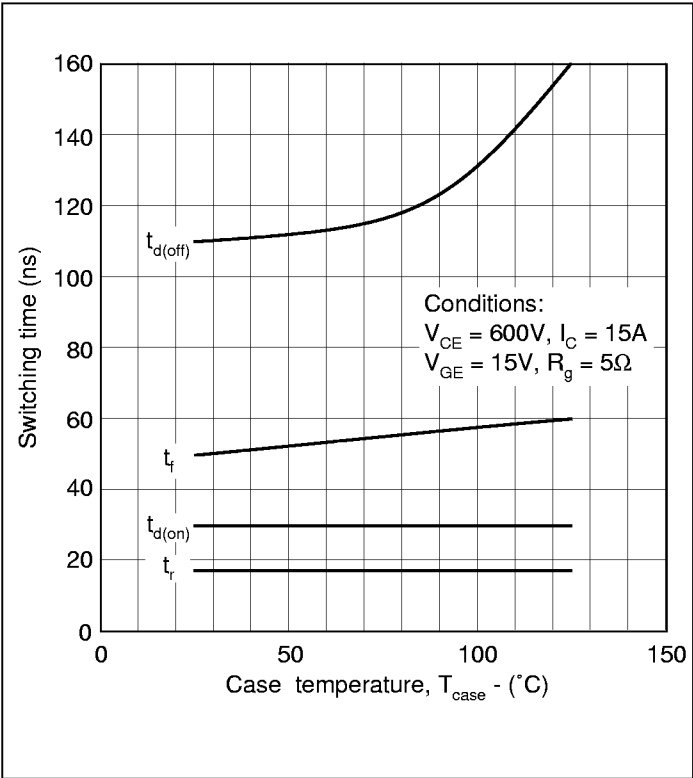


Fig.13 Typical switching time vs case temperature

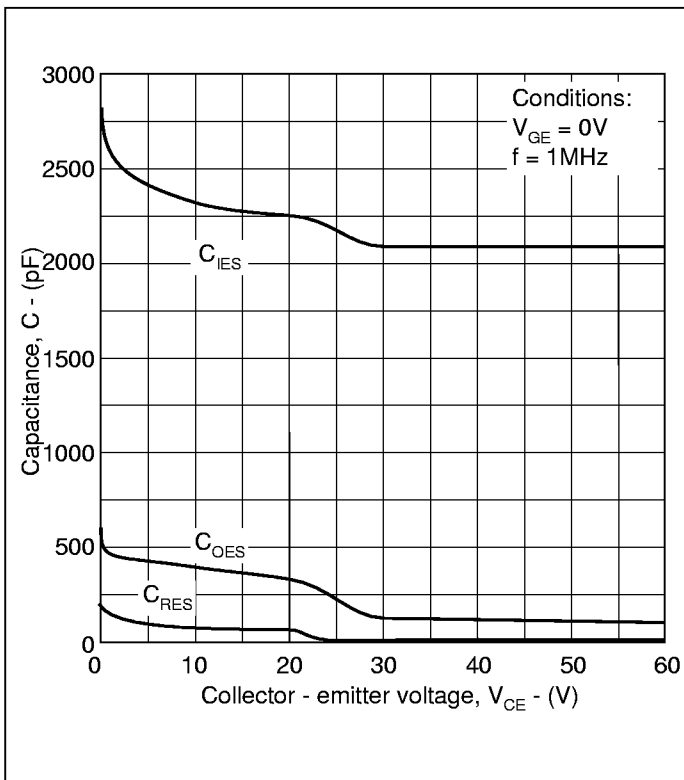


Fig.14 Typical capacitance

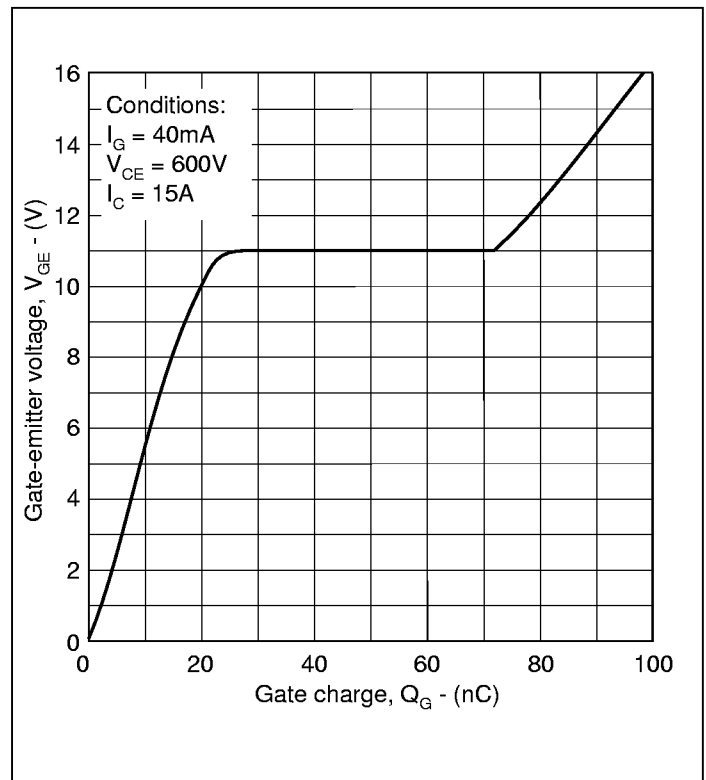


Fig.15 Typical gate charge

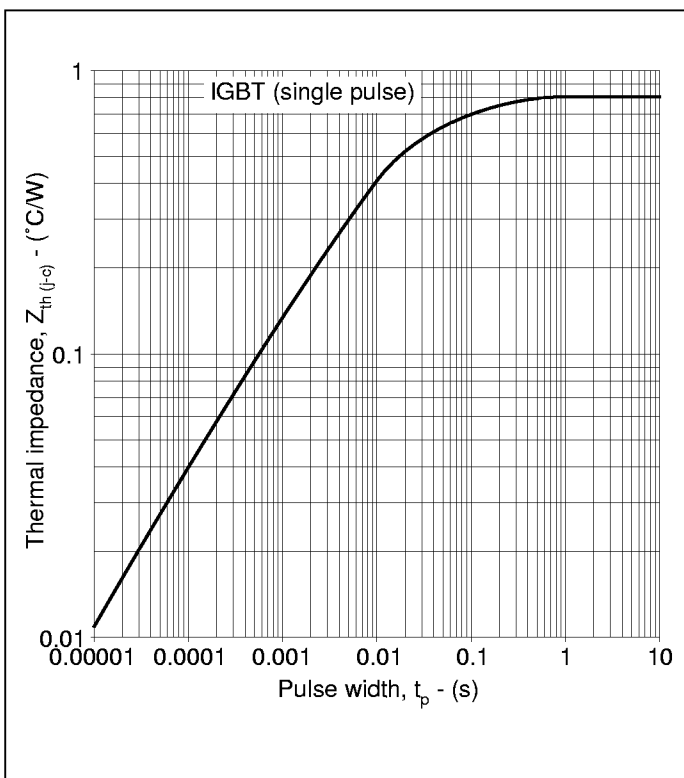


Fig.16 Transient thermal impedance - junction to case

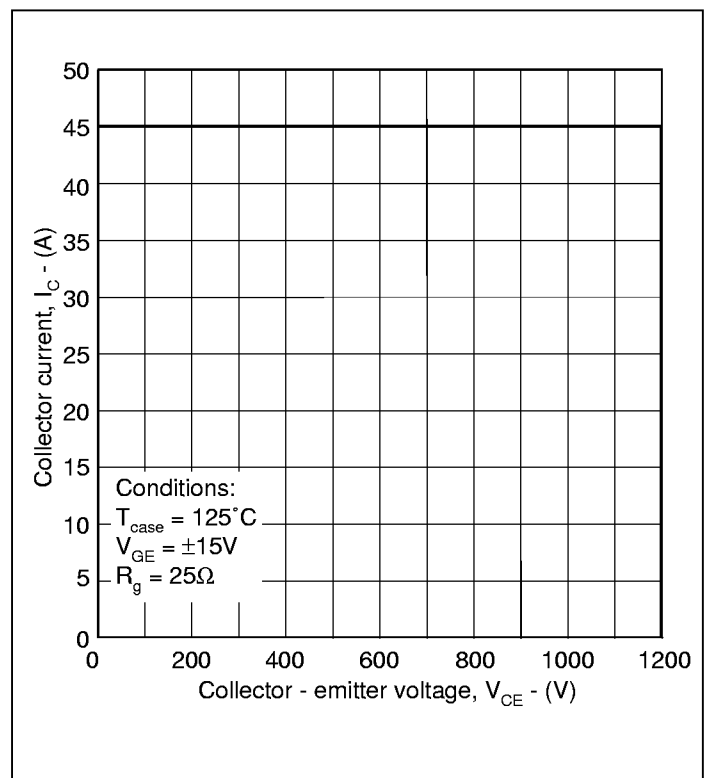


Fig.17 Reverse bias safe operating area

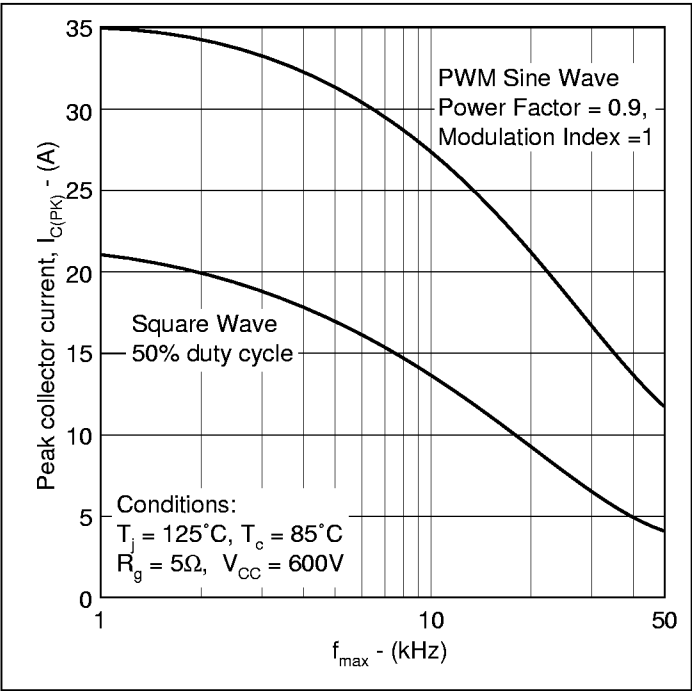


Fig.18 Three Phase PWM inverter operating frequency

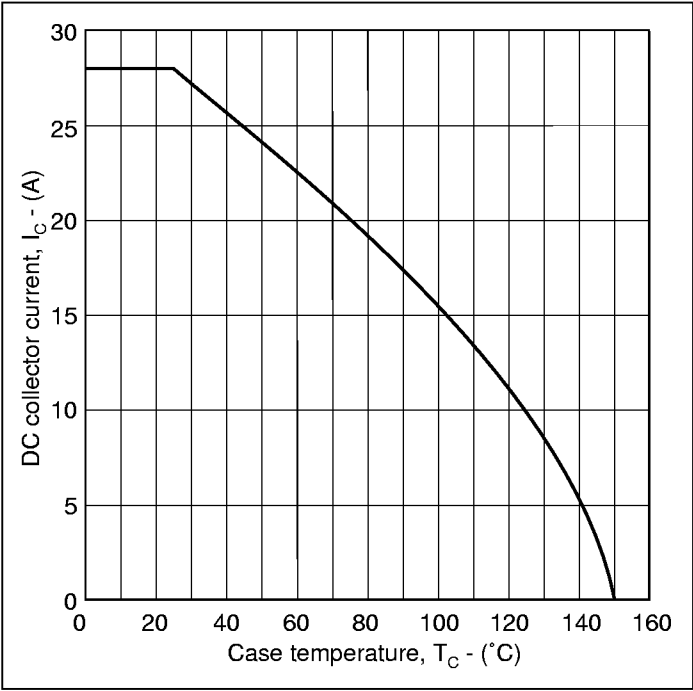
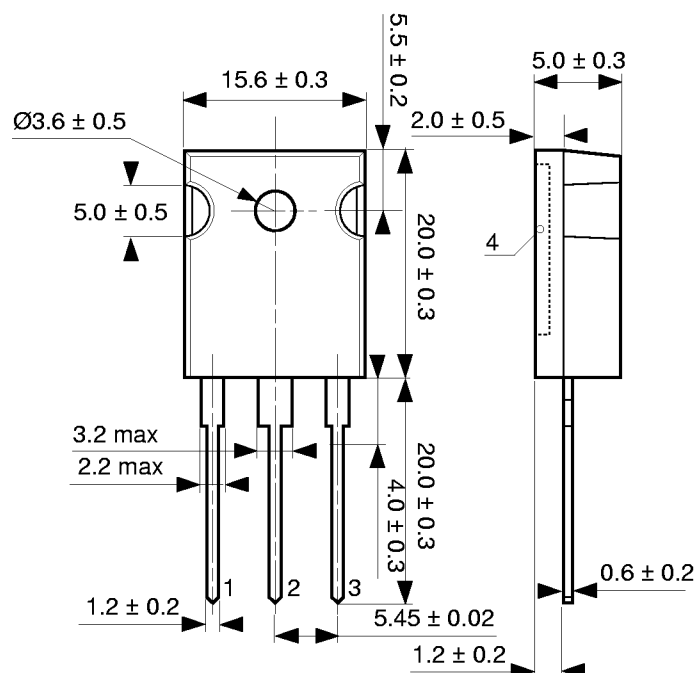


Fig.19 DC current rating vs case temperature

PACKAGE OUTLINE - TO247

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise.
DO NOT SCALE.



Terminal 1 - Gate
Terminal 2 - Collector
Terminal 3 - Emitter
Terminal 4 - Collector



HEADQUARTERS POWER OPERATIONS

MITEL SEMICONDUCTOR

Doddington Road, Lincoln,
LN6 3LF, United Kingdom.
Tel: + 44 (0)1522 500500
Fax: + 44 (0)1522 500550

Internet: <http://www.mitelsemi.com>

e-mail: power_solutions@mitel.com

POWER PRODUCT CUSTOMER SERVICE CENTRES

- **FRANCE, BENELUX & SPAIN:** Tel: + 33 (0)1 69 18 90 00 Fax : +33 (0)1 64 46 54 50
- **NORTH AMERICA:** Tel: 011-800-5554-5554 Fax: 011-800-5444-5444
- **UK, GERMANY, REST OF WORLD:** Tel: + 44 (0)1522 500500 Fax : + 44 (0)1522 500020

ADVANCE INFORMATION - The product design is complete and final characterisation for volume production is well in hand. These are supported by agents and distributors in major countries world-wide.

© Mitel 1999 Publication No. DS5053-1 Issue No. 1.2 January 1999

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